- spreading layer
- 6. The high brightness light emitting diode (LED) of claim 1, wherein a material system of said first active layer
- 7. The high brightness light emitting diode (LED) of claim 1, wherein a material system of said second active layer
- 8. The high brightness light emitting diode (LED) of claim 1, wherein a material system of said first cladding layer.....
- 9. The high brightness light emitting diode (LED) of claim 1, wherein a material system of said second cladding layer......
- 10. A high brightness light emitting diode (LED) emitting light of white or desire color, comprising:
 - a submount;
 - an epitaxial layer comprising a first-type cladding layer,.....
- 11. The high brightness light emitting diode (LED) of claim 10, further comprises a transition active layer.....
- 12. The high brightness light emitting diode (LED) of claim 11, wherein a material system of said transition active layer......
- 13. The high brightness light emitting diode (LED) of claim 10, further comprises a current spreading layer
- 14. The high brightness light emitting diode (LED) of claim 10, further comprises a reflector/Ohmic layer
- 15. The high brightness light emitting diode (LED) of claim 14, wherein said reflector/Ohmic layer comprises materials
- 16. The high brightness light emitting diode (LED) of claim 10, wherein a material system of said first active layer.....
- 17. The high brightness light emitting diode (LED) of claim 10, wherein a material system of said second active layer......
- 18. The high brightness light emitting diode (LED) of claim 10, wherein a material system of said first cladding layer......
- 19. The high brightness light emitting diode (LED) of claim 10, wherein a material system of said second cladding layer
- 20. The high brightness light emitting diode (LED) of claim 10, wherein said first electrode is patterned
- 21. The high brightness light emitting diode (LED) of claim 20, wherein said patterned first electrode is......
- 22. The high brightness light emitting diode (LED) of claim 20, wherein said patterned first electrode is